MMSD103T1G, SMMSD103T1G

High Voltage Switching Diode

Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|----------------------------|------------------------|-------|------|
| Continuous Reverse Voltage | V _R | 250 | V |
| Peak Forward Current | IF | 200 | mA |
| Peak Forward Surge Current | I _{FM(surge)} | 625 | mA |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Value | Unit |
|--|----------------------------------|-------------|-------------|
| Forward Power Dissipation, FR-5 Board (Note 1) @ T _A = 25°C Derate above 25°C | P _F | 400 3.2 | mW mW/°C |
| Thermal Resistance, Junction-to-Case | $R_{	heta JL}$ | 174 | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 492 | °C/W |
| Junction and Storage Temperature Range | T _{J,} T _{stg} | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.



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SOD-123 CASE 425 STYLE 1



MARKING DIAGRAM



JS = Device Code
M = Date Code
Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|----------------------|-----------------------|
| MMSD103T1G | SOD-123 (Pb-Free) | 3,000 / Tape & Reel |
| SMMSD103T1G | SOD-123 (Pb-Free) | 3,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

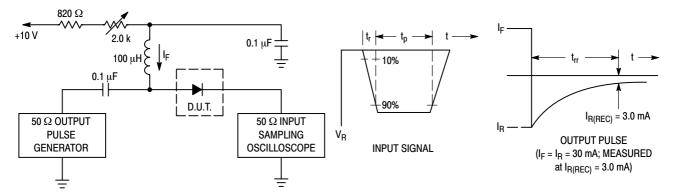
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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-------------------|--------|--------------|------|
| OFF CHARACTERISTICS | <u> </u> | | | |
| Reverse Voltage Leakage Current (V _R = 200 V) (V _R = 200 V, T _J = 150°C) | I _R | _ _ | 1.0 100 | μΑ |
| Reverse Breakdown Voltage ($I_{BR} = 100 \mu A$) | V _(BR) | 250 | - | V |
| Forward Voltage (I _F = 100 mA) (I _F = 200 mA) | V _F | - - | 1000 1250 | mV |
| Diode Capacitance (V _R = 0, f = 1.0 MHz) | C _D | _ | 5.0 | pF |
| Reverse Recovery Time (I _F = I _R = 30 mA, R _L = 100 Ω) | t _{rr} | _ | 50 | ns |



Notes: 1. A 2.0 $k\Omega$ variable resistor adjusted for a Forward Current (IF) of 30 mA.

2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 30 mA.

3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

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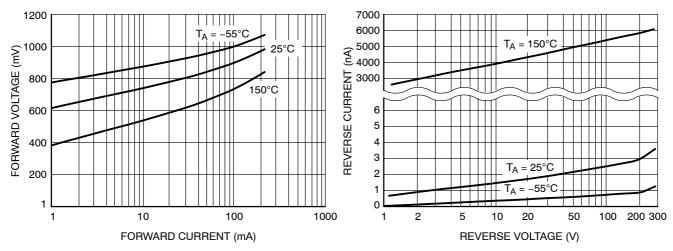


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

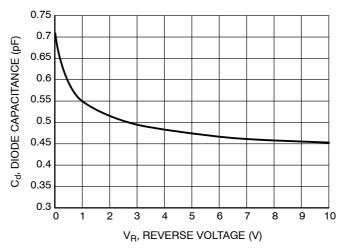


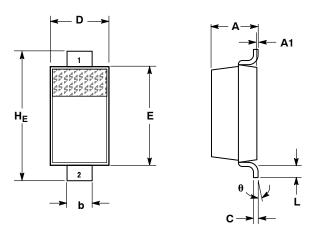
Figure 4. Diode Capacitance



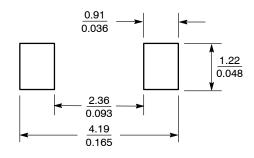
SOD-123 CASE 425-04 ISSUE G

DATE 07 OCT 2009





SOLDERING FOOTPRINT*



SCALE 10:1

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

| | MILLIMETERS INCHES | | | | | |
|-----|--------------------|------|------|-------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.94 | 1.17 | 1.35 | 0.037 | 0.046 | 0.053 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.51 | 0.61 | 0.71 | 0.020 | 0.024 | 0.028 |
| С | | | 0.15 | | | 0.006 |
| D | 1.40 | 1.60 | 1.80 | 0.055 | 0.063 | 0.071 |
| Е | 2.54 | 2.69 | 2.84 | 0.100 | 0.106 | 0.112 |
| HE | 3.56 | 3.68 | 3.86 | 0.140 | 0.145 | 0.152 |
| L | 0.25 | | | 0.010 | | |
| θ | 0° | | 10° | 0° | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1: PIN 1. CATHODE 2. ANODE

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| DESCRIPTION: | SOD-123 | | PAGE 1 OF 1 | |

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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